# 74AUP1G125

# Low-power buffer/line driver; 3-state

Rev. 9 — 14 January 2022

**Product data sheet** 

### 1. General description

The 74AUP1G125 is a single buffer/line driver with 3-state output. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

### 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- · Complies with JEDEC standards:
  - JESD8-12 (0.8 V to 1.3 V)
  - JESD8-11 (0.9 V to 1.65 V)
  - JESD8-7 (1.2 V to 1.95 V)
  - JESD8-5 (1.8 V to 2.7 V)
  - JESD8-B (2.7 V to 3.6 V)
- ESD protection:
  - HBM JESD22-A114F Class 3A exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; I<sub>CC</sub> = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- · Input-disable feature allows floating input conditions
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- · Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



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# 3. Ordering information

**Table 1. Ordering information** 

Type number	Package	Package								
	Temperature range	Name	Description	Version						
74AUP1G125GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1						
74AUP1G125GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886						
74AUP1G125GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	SOT1115						
74AUP1G125GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202						
74AUP1G125GX	-40 °C to +125 °C	X2SON5	plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.32 mm	SOT1226-3						

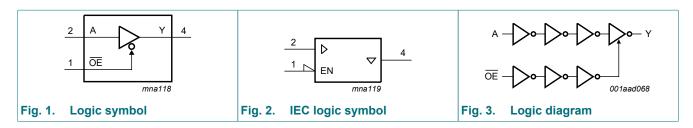
# 4. Marking

Table 2. Marking

auto at marking						
Type number	Marking code [1]					
74AUP1G125GW	рМ					
74AUP1G125GM	рМ					
74AUP1G125GN	рМ					
74AUP1G125GS	pM					
74AUP1G125GX	рМ					

<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 5. Functional diagram

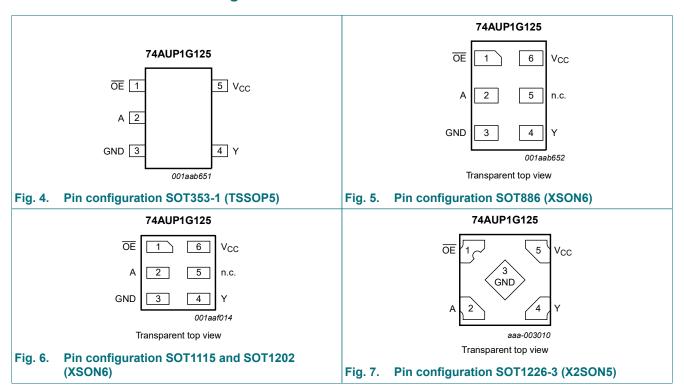


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# 6. Pinning information

### 6.1. Pinning



### 6.2. Pin description

Table 3. Pin description

Symbol	Pin	Pin			
	TSSOP5 and X2SON5	XSON6			
ŌĒ	1	1	output enable input		
A	2	2	data input		
GND	3	3	ground (0 V)		
Υ	4	4	data output		
n.c.	-	5	not connected		
V <sub>CC</sub>	5	6	supply voltage		

## 7. Functional description

#### **Table 4. Function table**

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = Don't \ care; \ Z = high-impedance \ OFF-state.$ 

Input OE		Output
ŌE	A	Υ
L	L	L
L	Н	Н
Н	X	Z

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## 8. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
Vo	output voltage	Active mode [1]	-0.5	V <sub>CC</sub> + 0.5	V
		Power-down mode; V <sub>CC</sub> = 0 V [1]	-0.5	+4.6	V
Io	output current	V <sub>O</sub> = 0 V to V <sub>CC</sub>	-	±20	mA
I <sub>CC</sub>	supply current		-	+50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$ [2]	-	250	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SOT886 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: Ptot derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

For SOT1226-3 (X2SON5) package: Ptot derates linearly with 3.0 mW/K above 67 °C.

## 9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V <sub>CC</sub>	V
		Power-down mode; V <sub>CC</sub> = 0 V	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 0.8 V to 3.6 V	0	200	ns/V

<sup>[2]</sup> For SOT353-1 (TSSOP5) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

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## 10. Static characteristics

**Table 7. Static characteristics** 

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T <sub>amb</sub> = 2	25 °C						
V <sub>IH</sub>	HIGH-level input	V <sub>CC</sub> = 0.8 V		0.70 × V <sub>CC</sub>	-	-	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V		0.65 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V		1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V		2.0	-	-	V
V <sub>IL</sub>	LOW-level input	V <sub>CC</sub> = 0.8 V		-	-	0.30 × V <sub>CC</sub>	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V		-	-	0.35 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V		-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V		-	-	0.9	V
V <sub>OH</sub>	HIGH-level output	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>					
	voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V		V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V		0.75 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V		1.11	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V		1.32	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V		2.05	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V		1.9	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V		2.72	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V		2.6	-	-	V
	LOW-level output	$V_I = V_{IH}$ or $V_{IL}$					
	voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V		-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V		-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V		-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V		-	-	0.31	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V		-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V		-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V		-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V		-	-	0.44	V
l <sub>l</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V		-	-	±0.1	μA
l <sub>OZ</sub>	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$		-	-	±0.1	μΑ
l <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V		-	-	±0.2	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	$V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V		-	-	±0.2	μΑ
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V		-	-	0.5	μΑ
Δl <sub>CC</sub>	additional supply current	data input; $V_I = V_{CC} - 0.6 \text{ V}$ ; $I_O = 0 \text{ A}$ ; $V_{CC} = 3.3 \text{ V}$	[1]	-	-	40	μΑ
		$\overline{OE}$ input; $V_I = V_{CC} - 0.6 \text{ V}$ ; $I_O = 0 \text{ A}$ ; $V_{CC} = 3.3 \text{ V}$	[1]	-	-	110	μΑ
		all inputs; $V_I$ = GND to 3.6 V; $\overline{OE}$ = $V_{CC}$ ; $V_{CC}$ = 0.8 V to 3.6 V	[2]	-	-	1	μΑ

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Cı	input capacitance	$V_{CC}$ = 0 V to 3.6 V; $V_I$ = GND or $V_{CC}$		-	0.9	-	pF
Co	output capacitance	output enabled; V <sub>O</sub> = GND; V <sub>CC</sub> = 0 V		-	1.7	-	pF
		output disabled; $V_{CC}$ = 0 V to 3.6 V; $V_{O}$ = GND or $V_{CC}$		-	1.5	-	pF
T <sub>amb</sub> = -	40 °C to +85 °C		,				
V <sub>IH</sub>	HIGH-level input	V <sub>CC</sub> = 0.8 V	0.	70 × V <sub>CC</sub>	-	-	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	0.6	65 × V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V		1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V		2.0	-	-	V
V <sub>IL</sub>	LOW-level input	V <sub>CC</sub> = 0.8 V		-	-	0.30 × V <sub>CC</sub>	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V		-	-	0.35 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V		-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V		-	-	0.9	V
V <sub>OH</sub>	HIGH-level output	$V_I = V_{IH}$ or $V_{IL}$					
	voltage	$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	V	<sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V		7 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V		1.03	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V		1.30	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC}$ = 2.3 V		1.97	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V		1.85	-	-	V
		$I_{O}$ = -2.7 mA; $V_{CC}$ = 3.0 V		2.67	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V		2.55	-	-	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{IH}$ or $V_{IL}$					
	voltage	$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V		-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V		-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V		-	-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V		-	-	0.35	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V		-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V		-	-	0.45	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V		-	-	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V		-	-	0.45	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V		-	-	±0.5	μA
l <sub>OZ</sub>	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$		-	-	±0.5	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_1$ or $V_0 = 0 V$ to 3.6 V; $V_{CC} = 0 V$		-	-	±0.5	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	$V_1$ or $V_0 = 0 V$ to 3.6 V; $V_{CC} = 0 V$ to 0.2 V		-	-	±0.6	μΑ
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V		-	-	0.9	μΑ
ΔI <sub>CC</sub>	additional supply current	itional supply data input; $V_I = V_{CC} - 0.6 \text{ V}$ ; $I_O = 0 \text{ A}$ ;		-	-	50	μΑ
		$\overline{\text{OE}}$ input; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 3.3 V	[1]	-	-	120	μΑ
		all inputs; $V_I$ = GND to 3.6 V; $\overline{OE}$ = $V_{CC}$ ; $V_{CC}$ = 0.8 V to 3.6 V	[2]	-	-	1	μΑ

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = .	-40 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input	V <sub>CC</sub> = 0.8 V	0.75 × V	'cc -	-	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	0.70 × V	′cc -	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	-	-	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	-	-	V
V <sub>IL</sub>	LOW-level input	V <sub>CC</sub> = 0.8 V	-	-	0.25 × V <sub>CC</sub>	V
	voltage	V <sub>CC</sub> = 0.9 V to 1.95 V	-	-	0.30 × V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	0.9	V
V <sub>OH</sub>	HIGH-level output	$V_{I} = V_{IH}$ or $V_{IL}$				
	voltage	$I_O = -20 \mu A$ ; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	V <sub>CC</sub> - 0.	11 -	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.6 × V <sub>0</sub>	cc -	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	0.93	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.17	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.77	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.67	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.40	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.30	-	-	V
V <sub>OL</sub>	LOW-level output	$V_I = V_{IH}$ or $V_{IL}$				
	voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.33 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.50	V
l <sub>l</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.75	μA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.75	μA
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.75	μA
Δl <sub>OFF</sub>	additional power-off leakage current	$V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.75	μA
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	1.4	μA
ΔI <sub>CC</sub>	additional supply current	data input; $V_I = V_{CC} - 0.6 \text{ V}$ ; $I_O = 0 \text{ A}$ ; $V_{CC} = 3.3 \text{ V}$	[1] -	-	75	μA
			[1] -	-	180	μA
			[2] -	-	1	μA

One input at  $V_{CC}$  - 0.6 V, other input at  $V_{CC}$  or GND. To show  $I_{CC}$  remains very low when the input-disable feature is enabled.

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# 11. Dynamic characteristics

#### **Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 10.

Symbol	Parameter	Conditions		T <sub>amb</sub> = 25 °C			T <sub>amb</sub> = -40 °C to +85 °C		T <sub>amb</sub> = -40 °C to +125 °C	
			Min	Typ [1]	Max	Min	Max	Min	Max	
C <sub>L</sub> = 5 p	F									
t <sub>pd</sub>		A to Y; see <u>Fig. 8</u> [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	20.6	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.8	5.5	10.5	2.5	11.7	2.5	12.9	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.2	3.9	6.1	2.0	7.3	2.0	8.1	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.9	3.2	4.8	1.7	6.1	1.7	6.7	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	2.6	3.6	1.4	4.3	1.4	4.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.4	2.4	3.1	1.2	3.9	1.2	4.4	ns
t <sub>en</sub>	enable time	OE to Y; see Fig. 9 [3]								
	-	V <sub>CC</sub> = 0.8 V	-	69.9	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.1	6.1	11.8	2.9	13.9	2.9	15.4	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.5	4.2	6.6	2.3	7.7	2.3	8.3	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.1	3.4	5.1	2.0	6.2	2.0	6.8	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.8	2.6	3.7	1.7	4.5	1.7	5.0	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.7	2.4	3.1	1.7	3.5	1.7	3.9	ns
t <sub>dis</sub>	disable time	OE to Y; see Fig. 9 [4]								
		V <sub>CC</sub> = 0.8 V	-	14.3	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.7	4.3	6.5	2.7	7.3	2.7	8.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.1	3.2	4.4	2.1	5.1	2.1	5.7	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.0	3.0	4.3	2.0	5.0	2.0	5.7	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.4	2.2	2.9	1.4	3.3	1.4	4.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.7	2.5	3.2	1.7	3.4	1.7	3.9	ns
C <sub>L</sub> = 10	pF							,		
t <sub>pd</sub>		A to Y; see <u>Fig. 8</u> [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	24.0	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.2	6.4	12.3	3.0	13.8	3.0	15.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.1	4.5	7.3	1.9	8.5	1.9	9.4	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.9	3.8	5.5	1.7	6.8	1.7	7.6	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.1	3.2	4.2	1.6	5.3	1.6	5.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.8	3.0	3.8	1.6	4.6	1.6	5.2	ns
t <sub>en</sub>	enable time	OE to Y; see Fig. 9 [3]								
		V <sub>CC</sub> = 0.8 V	-	73.7	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.6	6.9	13.5	3.4	15.8	3.4	17.5	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.3	4.8	7.7	2.2	8.6	2.2	9.4	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.0	3.9	5.8	1.9	6.8	1.9	7.4	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.8	3.2	4.3	1.7	5.3	1.7	5.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.7	3.0	3.9	1.7	4.3	1.7	4.8	ns

### Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C		T <sub>amb</sub> = -40 °C to +85 °C		T <sub>amb</sub> = -40 °C to +125 °C		Unit	
			Min	Typ [1]	Max	Min	Max	Min	Max	
t <sub>dis</sub>	disable time	OE to Y; see Fig. 9 [4]								
		V <sub>CC</sub> = 0.8 V	-	32.7	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.4	5.4	7.9	3.4	8.8	3.4	9.9	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.2	4.1	5.5	2.2	6.2	2.2	7.1	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.2	4.2	5.6	1.9	6.3	1.9	7.1	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	3.0	3.8	1.7	4.5	1.7	5.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.1	3.8	4.8	1.7	5.0	1.7	5.6	ns
C <sub>L</sub> = 15	pF									
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	27.4	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.6	7.2	14.1	3.3	15.8	3.3	17.5	ns
	-	V <sub>CC</sub> = 1.4 V to 1.6 V	3.0	5.1	8.1	2.5	9.8	2.5	10.9	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.2	4.3	6.3	2.0	7.9	2.0	8.8	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.0	3.7	4.9	1.8	6.0	1.8	6.7	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	3.5	4.4	1.8	5.4	1.8	6.1	ns
t <sub>en</sub>	enable time	OE to Y; see Fig. 9 [3]								
		V <sub>CC</sub> = 0.8 V	-	77.5	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.0	7.7	15.2	3.7	17.6	3.7	19.6	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.0	5.3	8.4	2.5	9.8	2.5	10.7	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.3	4.4	6.5	2.1	7.7	2.1	8.5	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.1	3.6	5.0	2.0	6.1	2.0	6.8	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	3.5	4.5	1.9	4.9	1.9	5.5	ns
t <sub>dis</sub>	disable time	OE to Y; see Fig. 9 [4]								
		V <sub>CC</sub> = 0.8 V	-	60.8	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.3	6.5	9.2	3.7	10.3	3.7	11.6	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.0	5.0	6.5	2.5	7.4	2.5	8.4	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	3.0	5.3	6.6	2.1	7.4	2.1	8.9	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.1	3.8	4.9	2.0	5.1	2.0	6.4	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.9	5.0	6.2	1.9	6.6	1.9	7.4	ns
C <sub>L</sub> = 30	pF									
t <sub>pd</sub>	propagation	A to Y; see <u>Fig. 8</u> [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	37.4	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.8	9.5	19.0	4.4	21.6	4.4	24.0	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	4.0	6.7	10.8	3.0	13.0	3.0	14.5	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.9	5.6	8.4	2.6	10.3	2.6	11.5	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.7	4.8	6.3	2.5	7.8	2.5	8.7	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.7	4.6	5.8	2.5	7.5	2.5	8.3	ns

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**Product data sheet** 

#### Low-power buffer/line driver; 3-state

Symbol	Parameter	Conditions	T,	T <sub>amb</sub> = 25 °C		T <sub>amb</sub> = -40 °C to +85 °C		T <sub>amb</sub> = -40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
t <sub>en</sub>	enable time	OE to Y; see Fig. 9 [3]								
		V <sub>CC</sub> = 0.8 V	-	88.9	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	5.2	9.9	19.8	4.8	22.8	4.8	25.3	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	4.0	6.8	10.8	3.1	12.6	3.1	14.1	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	3.0	5.6	8.5	2.8	10.2	2.8	11.3	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.7	4.8	6.5	2.6	7.8	2.6	8.8	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.7	4.6	6.0	2.6	6.9	2.6	7.7	ns
t <sub>dis</sub>	disable time	OE to Y; see Fig. 9 [4]								
		V <sub>CC</sub> = 0.8 V	-	49.9	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	6.0	9.9	13.3	4.8	14.8	4.8	16.5	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	4.4	7.7	9.6	3.1	10.7	3.1	12.1	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	5.1	8.7	11.1	2.8	12.4	2.8	13.8	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	3.6	6.2	7.4	2.6	8.6	2.6	9.6	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	5.2	8.7	10.5	2.6	10.8	2.6	13.1	ns
T <sub>amb</sub> = 2	5 °C					'			-	
C <sub>PD</sub>	power dissipation capacitance	f = 1  MHz;								
		V <sub>CC</sub> = 0.8 V	-	2.7	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	2.8	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	2.9	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	3.0	-	-	-	-	-	pF
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	3.6	-	-	-	-	-	pF
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	4.2	-	-	-	-	-	pF

- All typical values are measured at nominal V<sub>CC</sub>.

- [1] All typical values are measured at nominal V<sub>CC</sub>.
  [2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.
  [3] t<sub>en</sub> is the same as t<sub>PZH</sub> and t<sub>PZL</sub>.
  [4] t<sub>dis</sub> is the same as t<sub>PHZ</sub> and t<sub>PLZ</sub>.
  [5] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).
  P<sub>D</sub> = C<sub>PD</sub> × V<sub>CC</sub> <sup>2</sup> × f<sub>i</sub> × N + Σ(C<sub>L</sub> × V<sub>CC</sub> <sup>2</sup> × f<sub>o</sub>) where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

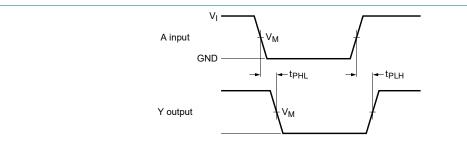
V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$  = sum of the outputs.

Low-power buffer/line driver; 3-state

### 11.1. Waveforms and test circuit

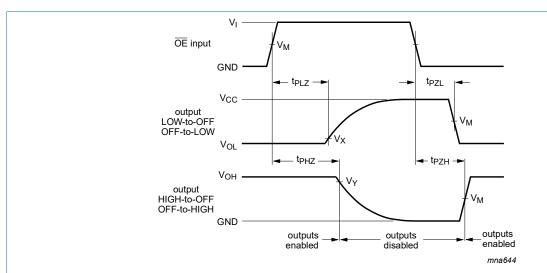


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Measurement points are given in Table 9.

Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Fig. 8. The data input (A) to output (Y) propagation delays



Measurement points are given in <u>Table 9</u>.

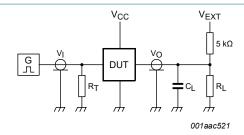
Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Fig. 9. Enable and disable times

**Table 9. Measurement points** 

Supply voltage	Input	Input			Output		
V <sub>CC</sub>	V <sub>M</sub>	V <sub>I</sub>	$t_r = t_f$	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>	
0.8 V to 1.6 V	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns	0.5 × V <sub>CC</sub>	V <sub>OL</sub> + 0.1 V	V <sub>OH</sub> - 0.1 V	
1.65 V to 2.7 V	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns	0.5 × V <sub>CC</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> - 0.15 V	
3.0 V to 3.6 V	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns	0.5 × V <sub>CC</sub>	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> - 0.3 V	

#### Low-power buffer/line driver; 3-state



Test data is given in Table 10.

Definitions for test circuit:

R<sub>L</sub> = Load resistance;

C<sub>L</sub> = Load capacitance including jig and probe capacitance;

R<sub>T</sub> = Termination resistance should be equal to the output impedance Z<sub>o</sub> of the pulse generator;

V<sub>EXT</sub> = External voltage for measuring switching times.

Fig. 10. Test circuit for measuring switching times

#### Table 10. Test data

Supply voltage	Load	V <sub>EXT</sub>			
V <sub>CC</sub>	CL	R <sub>L</sub> [1]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V <sub>CC</sub>

[1] For measuring enable and disable times  $R_L$  = 5 k $\Omega$ . For measuring propagation delays, setup and hold times and pulse width  $R_L$  = 1 M $\Omega$ .

Low-power buffer/line driver; 3-state

# 12. Package outline

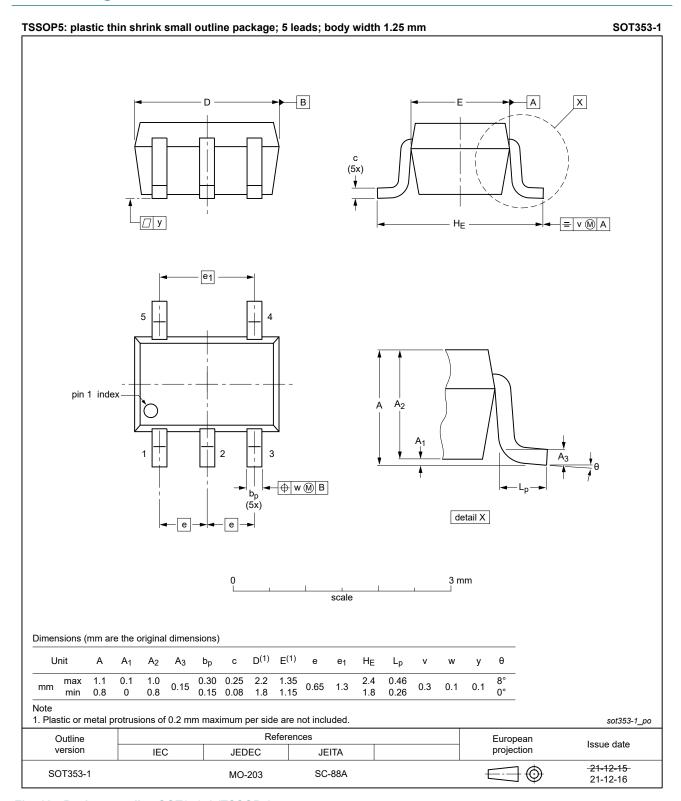


Fig. 11. Package outline SOT353-1 (TSSOP5)

#### Low-power buffer/line driver; 3-state

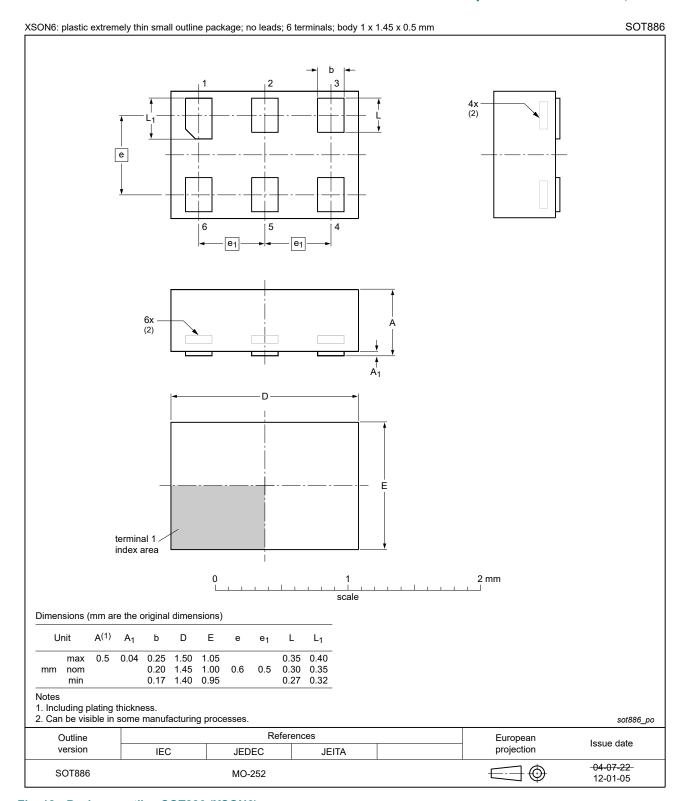


Fig. 12. Package outline SOT886 (XSON6)

Low-power buffer/line driver; 3-state

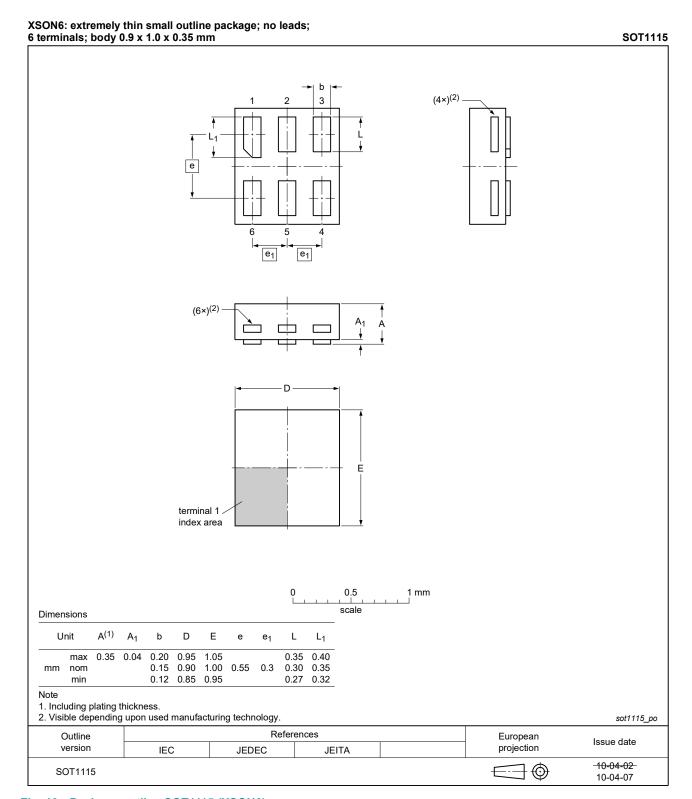


Fig. 13. Package outline SOT1115 (XSON6)

Low-power buffer/line driver; 3-state

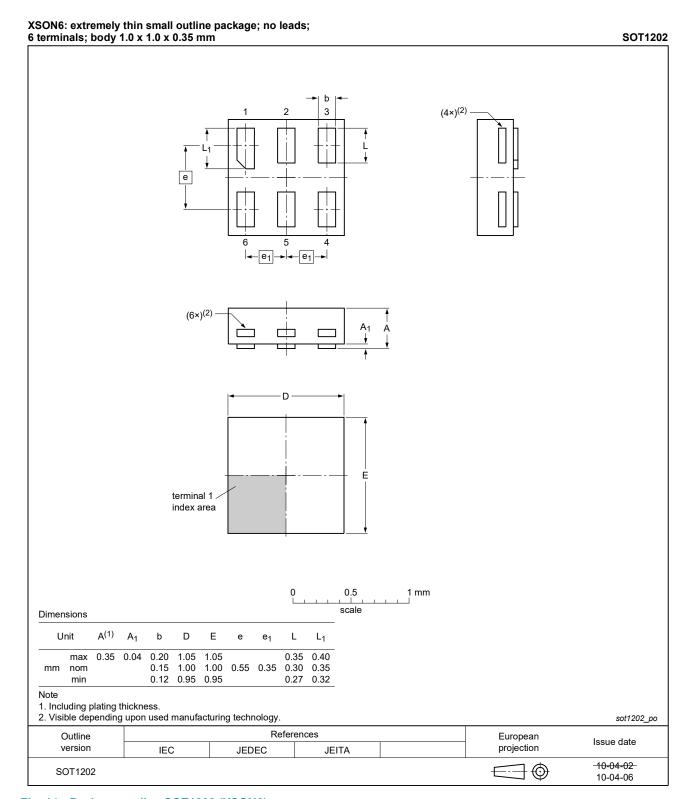


Fig. 14. Package outline SOT1202 (XSON6)

Low-power buffer/line driver; 3-state

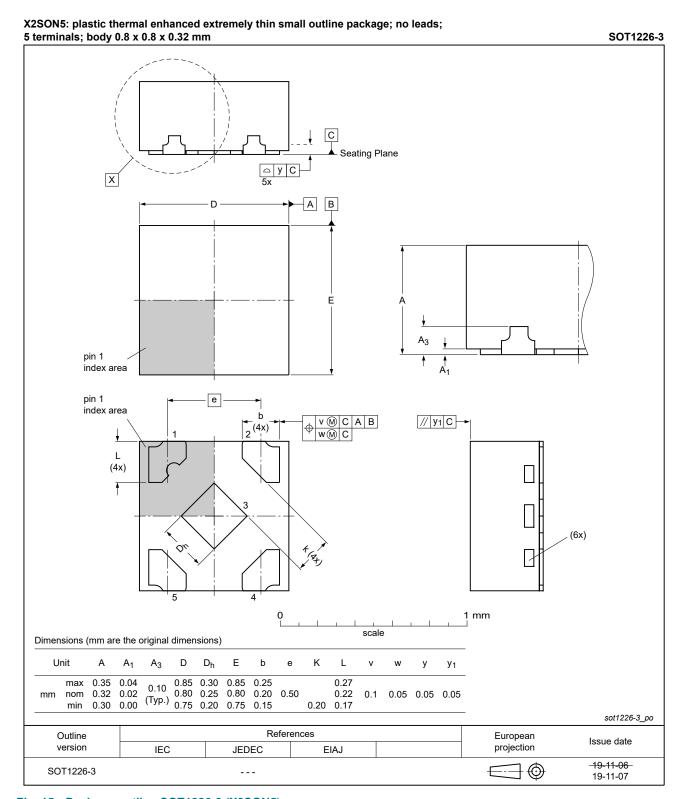


Fig. 15. Package outline SOT1226-3 (X2SON5)

Low-power buffer/line driver; 3-state

### 13. Abbreviations

#### **Table 11. Abbreviations**

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

## 14. Revision history

### Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74AUP1G125 v.9	20220114	Product data sheet	-	74AUP1G125 v.8	
Modifications:	• <u>Fig. 11</u> : Pac	• Fig. 11: Package outline drawing for SOT353-1 (TSSOP5) has changed.			
74AUP1G125 v.8	20210421	Product data sheet	-	74AUP1G125 v.7	
Modifications:	<ul><li>Type number</li><li>Section 1 up</li></ul>	<ul> <li>SOT1226 (X2SON5) package changed to SOT1226-3 (X2SON5) package.</li> <li>Type number 74AUP1G125GF (SOT891 / XSON6) removed.</li> <li>Section 1 updated.</li> <li>Table 5: Derating values for P<sub>tot</sub> total power dissipation updated.</li> </ul>			
74AUP1G125 v.7	20180813	Product data sheet	-	74AUP1G125 v.6	
Modifications:	guidelines o	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>			
74AUP1G125 v.6	20120815	Product data sheet	-	74AUP1G125 v.5	
Modifications:	Errata in ge	Errata in general description corrected			
74AUP1G125 v.5	20120731	Product data sheet	-	74AUP1G125 v.4	
Modifications:		<ul> <li>Added type number 74AUP1G125GX (SOT1226)</li> <li>Package outline drawing of SOT886 (Fig. 12) modified.</li> </ul>			
74AUP1G125 v.4	20111129	Product data sheet	-	74AUP1G125 v.3	
74AUP1G125 v.3	20100901	Product data sheet	-	74AUP1G125 v.2	
74AUP1G125 v.2	20060630	Product data sheet	-	74AUP1G125 v.1	
74AUP1G125 v.1	20050718	Product data sheet	-	-	

#### Low-power buffer/line driver; 3-state

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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### Low-power buffer/line driver; 3-state

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